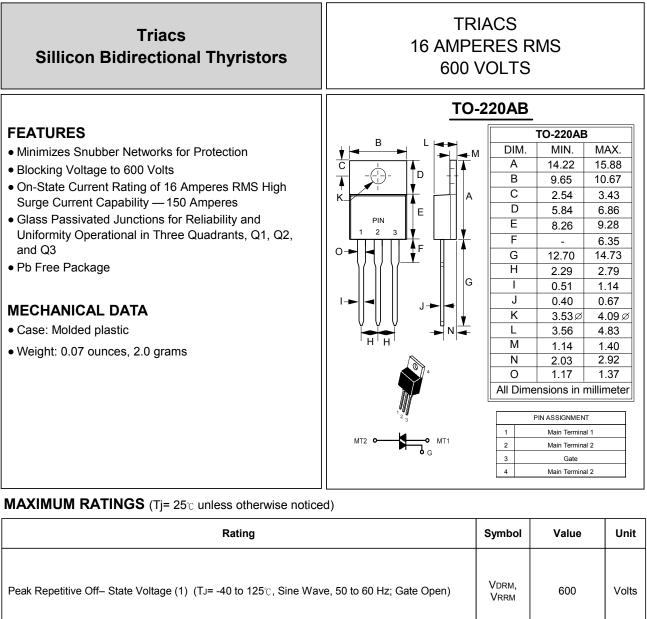
## LITE ON SEMICONDUCTOR

### T16M35T600B



On-State RMS Current (Tc = +80°c) Full Cycle Sine Wave 50 to 60 Hz	It(rms	5) 16	Amp
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, TJ= $25^{\circ}$ C) Preceded and followed by rated current.	Ітям	150	Amps
Circuit Fusing Consideration (t = 8.3 ms)	l t	93	As
Peak Gate Power (Tc = +80 $^\circ\!\mathbb{C}$ , Tp $\leq$ 1.0 us)	Рсм	20	Watt
Average Gate Power (Tc = +80°C, t=8.3 ms)	PG(AV	0.5	Watt
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	Tstg	-40 to +150	°C
Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking	F	REV. 4, Oct-2010, KTXC21	

voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction to Case - Junction to Ambient	RthJC RthJA	2.0 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	T∟	260	°C

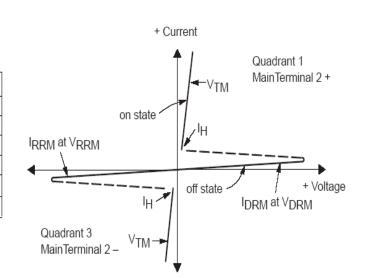
#### **ELECTRICAL CHARACTERISTICS** (TJ=25°C unless otherwise noted, Electrical apply in both directions)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Peak Reptitive Forward or Reverse Blocking Current TJ=25°C (VD=Rated VDRM, VRRM; Gate Open) TJ=125°C	IDRM IRRM			0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage (ITM=± 21 A Peak @Tp $\leq$ 2.0 ms, Duty Cycle $\leq$ 2%)	Vtm		1.2	1.6	Volts
Gate Trigger Current (VD = 12Vdc; RL = 100 Ohms)	lgt1 lgt2 lgt3	5.0 5.0 5.0	12 16 20	35 35 35	mA
Gate Trigger Voltage (V <sub>D</sub> = 12 Vdc; RL =100 Ohms)	VGT1 VGT2 VGT3	0.5 0.5 0.5	0.75 0.72 0.82	1.5 1.5 1.5	Volts
Holding Current (VD = 12 V, Initiating Current = ± 150 mA, Gate Open)	Ін		20	50	mA
Latching Current (VD = 12 V, IG = 35 mA)	١L		25 40 24	50 80 50	mA

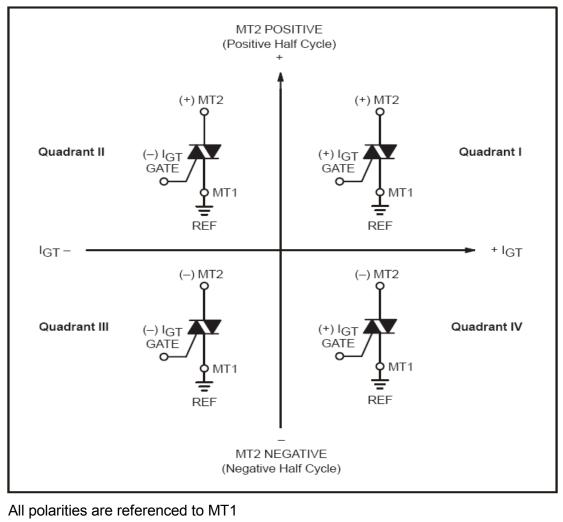
### DYNAMIC CHARACTERISTICS

Critical Rate of Change of Commutation Current (V <sub>D</sub> = Rated VDRM , $I_{TM}$ = 6.0 A, Commutating dv/dt = 24 V/ms, Gate Unenergized,Tc = 125°C,f = 250 Hz,Snubber: CL = 10 uf, LL =40 mH)	di/dt(c)	15	 	A/ms
Critical Rate of Rise of Commutation Voltage (VD = 67% VDRM , Exponential Waveform, Tc = 125°C)	dv/dt	600	 	V/us
Repettive Critical Rate of Rise of On-State Current IPK= 50A, PW=40 us; diG/dt = 200mA/us; f =60Hz	di/dt		 10	A/us

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
VTM	Maximum On State Voltage
ΙΗ	Holding Current



### **Quadrant Definitions**



Whith in -phase signal (using standard AC lines) quadrants I and III are used

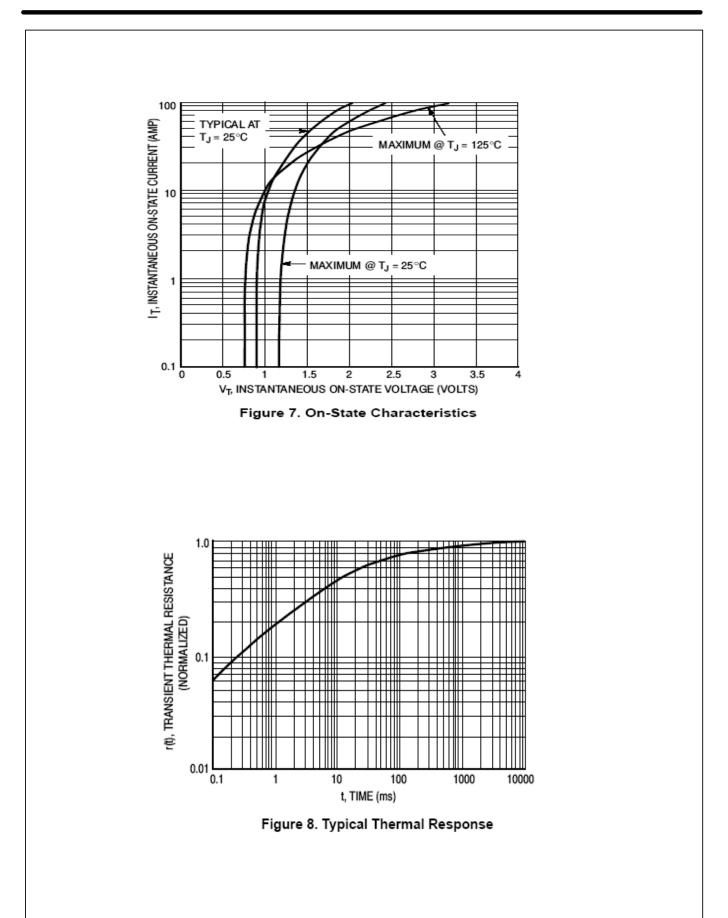
# **LITE ON**

### RATING AND CHARACTERISTIC CURVES T16M35T600B

#### 100 1.10 V<sub>GT</sub>, GATE TRIGGER VOLTAGE (VOLT) IGT, GATE TRIGGER CURRENT (mA) $\Omega^{2}$ 1.00 03 Q2 0.90 Q1 ç. 0.80 Q1 10 0.70 Q2 0.60 0.50 0.40 -40 -25 -10 50 95 110 125 -25 -10 50 110 -40 5 20 35 65 80 5 20 35 65 80 95 125 TJ, JUNCTION TEMPERATURE (°C) TJ, JUNCTION TEMPERATURE (°C) Figure 1. Typical Gate Trigger Current Figure 2. Typical Gate Trigger Voltage versus Junction Temperature versus Junction Temperature 100 100 Q2 Q1 LATCHING CURRENT (mA) HOLDING CURRENT (mA) MT2 NEGATIVE Q3 -10 MT2 POSITIVE -40 -25 -10 5 20 35 50 65 80 95 110 125 -40 -25 -10 5 20 35 50 65 80 95 110 125 TJ, JUNCTION TEMPERATURE (°C) TJ, JUNCTION TEMPERATURE (°C) Figure 3. Typical Holding Current Figure 4. Typical Latching Current versus Junction Temperature versus Junction Temperature 125 24 DC 22 120 PAV, AVERAGE POWER (WATTS) 20 180° 30° 115 T<sub>C</sub>, CASE TEMPERATURE (°C) 60° 18 120 110 90° 16 105 14 100 120° 12 95 180° 10 90 DC 8 90 85 6 60° 80 30° 75 2 70 L 0 0 2 4 6 8 10 12 14 16 2 4 6 8 10 12 14 16 IT (RMS), RMS ON-STATE CURRENT (AMP) IT(AV), AVERAGE ON-STATE CURRENT (AMP) Figure 5. Typical RMS Current Derating Figure 6. On-State Power Dissipation

## **LITE ON**

## RATING AND CHARACTERISTIC CURVES T16M35T-B SERIES



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